

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L19	5656	L18 AND (oxide\$4 NEAR20 \$5silicon NEAR20 nitride\$4)	US-PGPUB; USPAT	OR	OFF	2005/12/03 16:52
L20	1344	L19 AND (trench\$4 NEAR20 etch\$4)	US-PGPUB; USPAT	OR	OFF	2005/12/03 16:52
L21	1109	L20 AND (trench\$4 NEAR20 isolat\$4)	US-PGPUB; USPAT	OR	OFF	2005/12/03 14:55
L22	528	L21 AND (side\$1wall\$4 NEAR20 oxide\$4)	US-PGPUB; USPAT	OR	OFF	2005/12/03 15:01
L23	322	L22 AND (side\$1wall\$4 NEAR20 nitride\$4)	US-PGPUB; USPAT	OR	OFF	2005/12/03 15:01
L25	771	L21 AND ((side\$1wall\$4 OR line\$4) NEAR20 oxide\$4)	US-PGPUB; USPAT	OR	OFF	2005/12/03 15:01
L27	490	L25 AND ((side\$1wall\$4 OR line\$4) NEAR20 nitride\$4)	US-PGPUB; USPAT	OR	OFF	2005/12/03 15:02
L28	359	L27 AND (ion\$4 NEAR20 implant\$6)	US-PGPUB; USPAT	OR	OFF	2005/12/03 15:47
L29	13408	(438/221,296,427,637,369,370,690,691,692,700,702,706,710,719,723,724,745,753,756,757,770,775).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/12/03 15:04
L31	29	L28 AND L29	US-PGPUB; USPAT	OR	OFF	2005/12/03 15:04
L32	164	L27 AND (ion\$4 NEAR20 implant\$6)	US-PGPUB	OR	OFF	2005/12/03 15:48
L34	7034	(flash\$4 NEAR20 memor\$4) AND semi\$1conduct\$4	EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/03 16:51
L35	304	L34 AND (oxide\$4 NEAR20 \$5silicon NEAR20 nitride\$4)	EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/03 16:52
L36	36	L35 AND (trench\$4 NEAR20 etch\$4)	EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/03 16:52
L37	33741	(flash\$4 NEAR20 memor\$4) AND semi\$1conduct\$4	US-PGPUB; USPAT	OR	OFF	2005/12/03 16:53